Reflective Object Sensor Type OPB733T



Features:

- Unfocused for sensing diffuse surfaces
- Uses lensed devices for collimation of light beam
- Low-cost plastic housing
- Compact surface mount package 0.300" x 0.160" x 0.114"
- Typical peak emission wavelength 890nm
- High-speed phototransistor output
- Reduced visible ambient light sensitivity
- Optimal operating distance range 0.4" to 1.0"

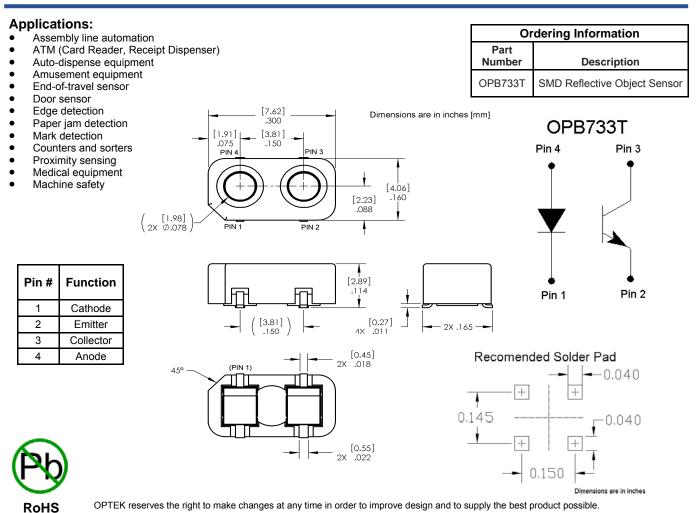


Description:

The **OPB733T** consists of an 890nm, Infrared Light Emitting Diode (LED) and an NPN silicon Phototransistor, which are mounted "side-by-side" on parallel axes in a miniature surface mount black plastic housing. The Phototransistor is molded in a dark epoxy package, which minimizes visible ambient light sensitivity. The phototransistor responds to radiation from the LED when a reflective object passes within its field of view. This unfocused reflective object sensor is ideal for non-contact detection of materials such as paper, labels, white plastic and many other reflective materials. The OPB733T sensors are packaged in 16mm tape on 7" diameter reels, 500 pcs per reel. Tape and Reel package

compatible with most automatic placement equipment.

Custom electrical, PCB assembly, wire and connectors are available. Contact your local OPTEK authorized representative or OPTEK for more information.





Absolute Maximum Ratings (T _A =25°C unless otherwise noted)				
Storage and Operating Temperature Range	-25° C to +85° C			
Soldering Temperature. (see reflow solder temperature profile figure)	260° C			
Input LED				
Forward DC Current	50 mA			
Peak Forward Current (1 µs pulse width, 300 pps)	1 A			
Reverse DC Voltage	5 V			
Power Dissipation ⁽²⁾	130 mW			
Output Phototransistor				
Collector-Emitter Voltage	30 V			
Emitter-Collector Voltage	5 V			
Collector DC Current	20 mA			
Power Dissipation ⁽³⁾	75 mW			

Electrical Characteristics (T_A = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input IR LED (see OP271 for additional information)						
V _F	Forward Voltage	-	-	1.7	V	I _F = 20 mA
I _R	Reverse Current	-	-	10	μA	V _R = 5 V
θ_{HP}	Emission angle at half power points	-	25	-	Degree	I _F = 20 mA
λ_{P}	Peak Emission Wavelength	-	890	-	nm	I _F = 10mA

Output Phototransistor (see OP571 for additional information)

V _{(BR)CE0}	Collector Emitter Breakdown Voltage	30	-	-	V	I _C = 100 μA
V _{(BR)ECO}	Emitter Collector Breakdown Voltage	5	-	-	v	I _E = 100 μA
I _{CEO}	Collector Dark Current	-	-	100	nA	V _{CE} = 10 V, I _F = 0
Tr	Rise Time	-	15	-	μs	$V_{CE} = 5$ Volts ⁽³⁾
Tf	Fall Time	-	15	-	μs	$I_{\rm C} = 1 \text{ mA}$ $R_{\rm L} = 1 K \Omega$

Coupled Characteristics

V _{CE(SAT)}	Collector Emitter Saturation Voltage	-	-	0.4		d = 0.5" (12.7 mm) $^{(1)(2)}$ I _C = 50 µA, I _F = 20 mA
I _{C(ON)}	On-State Collector Current	0.1	-	-	mA	d = 0.5" (12.7 mm) ⁽¹⁾⁽²⁾ I _F = 20 mA, V _{ce} = 5 V

Notes:

1. "d" is the distance from the assembly's top surface to the reflective surface

2. Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface.

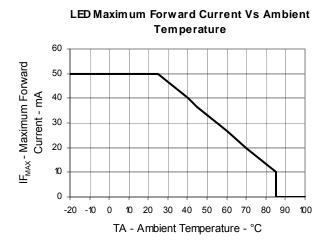
3. By designed but not tested.

4. Methanol or Isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones.

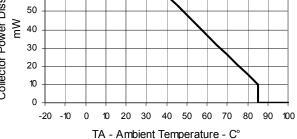
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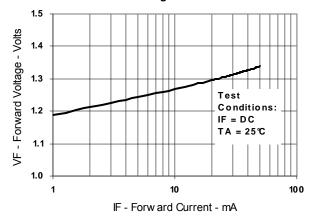
Typical Performance Curves



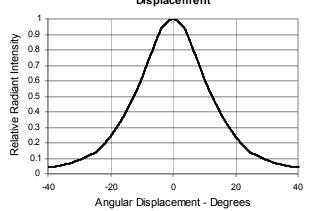
Phototransistor Collector Power Dissipation Vs Ambient Temperature 80 Collector Power Dissipation -70 60 50 М 40 30 20 10

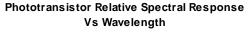


LED Forward Voltage Vs Forward Current

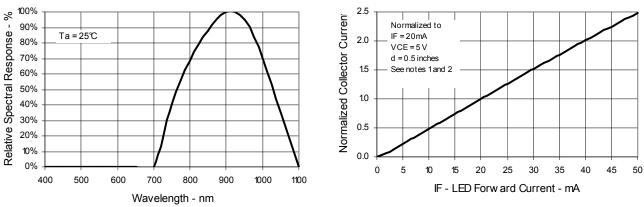


LED Relative Radiant Intensity Vs Angular Displacement





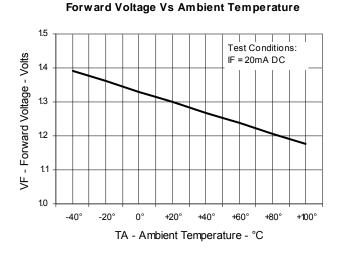




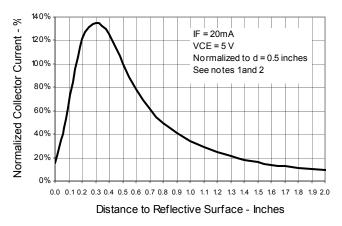
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Typical Performance Curves



Normalized Collector Current Vs Object Distance



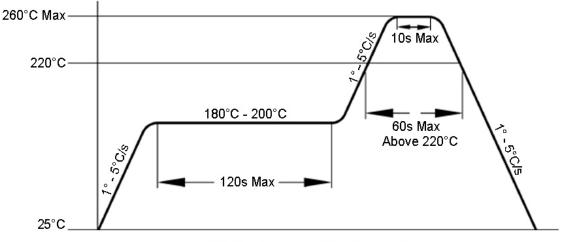
110 % Normalized Collector Current - % 100% 90% 80% 70% Normalized to: IF = 20mA 60% VCE=5V 50% d = 0.5 inches 40% See Note 1 and 2 30% 20% 10% 0% -40 -30 -20 -10 10 20 30 40 50 60 70 0 80 90 100 TA - Ambient Temperature - °C

Normalized Collector Current Vs Ambient Temperature



Soldering Method:

- Reflow soldering profile shown below. Soldering should not exceed this curve in temperature and time.
- Avoid soldering more than once.
- Avoid exerting any type of pressure on the optical lenses and contact leads before, during, and after soldering.



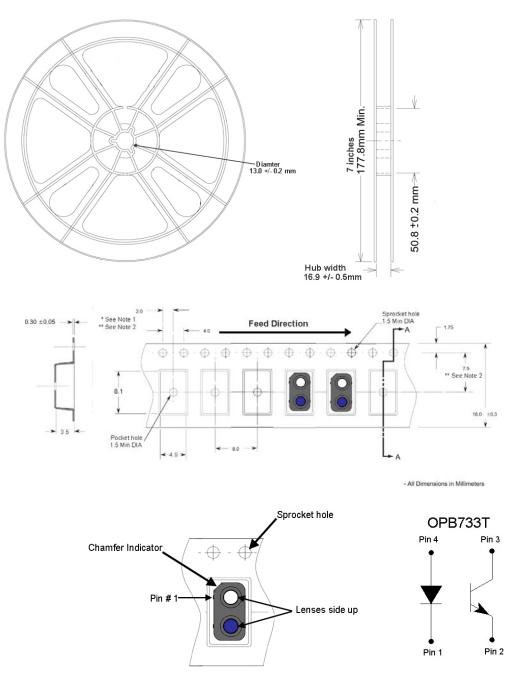
Lead Pb-free Reflow Solder Temperature Profile

Storage:

- Storage temperature and relative humidity (R.H.) conditions are: 5°C to 30°C and 70% R.H. or less.
- Moisture proof bag should be open only if devices are ready to be used. Devices should be utilized within three days after package has been opened.
- After opening the package, devices should be kept at a temperature of 5°C to 30°C and 60% R.H. or less.
- If the devices have exceed the storage time or the humidity card indicates 60% relative humidity level, all devices should go through a baking treatment outside the original package prior to usage. Baking treatment: 60°C +/- 5°C for 16 – 24 hours.



Tape and Reel package dimensions:



Notes:

- 1. * 10 sprocket hole pitch cumulative tolerance +/- 0.2mm.
- 2. ** Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.
- 3. Tolerances: +/- 0.1mm, except as noted.